# **ESD and Surge Protection Device, Bidirectional, 15 V**

Micro-Packaged Diodes for ESD Protection

# ESDL4151

The ESDL4151 is designed to protect voltage sensitive components that require low capacitance from ESD and transient voltage events. Excellent clamping capability, low capacitance, low leakage, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium. Because of its low capacitance, the part is well suited for use in high frequency designs such as USB 2.0/3.0 high speed applications.

#### Features

- Low Capacitance 0.8 pF (Typ)
- Low Clamping Voltage
- Small Body Outline Dimensions: 1.00 mm x 0.60 mm
- Low Body Height: 0.23 mm
- Stand-off Voltage: 15 V
- Protection for the following IEC Standards: IEC61000-4-2 Level 4: ±30 kV Contact Discharge IEC61000–4–5 (Lightning): 53 V Input (8/20 μs)
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

### **Typical Applications**

- USB 2.0/3.0
- MHL 2.0
- eSATA

#### MAXIMUM RATINGS

Rating		Symbol	Value	Unit
IEC 61000-4-2 (ESD)	Contact Air		±30 ±30	kV
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	–55 to +150	°C	
Lead Solder Temperature – Maximum (10 Second Duration)		TL	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

See Application Note AND8308/D for further description of survivability specs.



# **ON Semiconductor®**

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R5 = Specific Device Code M = Date Code

#### **ORDERING INFORMATION**

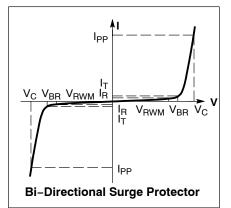
Device	Package	Shipping <sup>†</sup>	
ESDL4151MX4T5G	X3DFN2 (Pb–Free)	8000 / Tape & Reel	

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### **ELECTRICAL CHARACTERISTICS**

(T<sub>A</sub> = 25°C unless otherwise noted)

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Symbol	Parameter
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current
V <sub>C</sub>	Clamping Voltage @ I <sub>PP</sub>
V <sub>RWM</sub>	Working Peak Reverse Voltage
I <sub>R</sub>	Maximum Reverse Leakage Current @ V <sub>RWM</sub>
V <sub>BR</sub>	Breakdown Voltage @ I <sub>T</sub>
Ι <sub>Τ</sub>	Test Current



\*See Application Note AND8308/D for detailed explanations of datasheet parameters.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	V <sub>RWM</sub>	I/O Pin to GND			15	V
Breakdown Voltage	V <sub>BR</sub>	I <sub>T</sub> = 1 mA, I/O Pin to GND	15.5	16.6	19.5	V
Reverse Leakage Current	I <sub>R</sub>	@ 3.3 V, I/O Pin to GND @ 15 V, I/O Pin to GND		0.1 1.0	μΑ	
Clamping Voltage	V <sub>C</sub>	Per IEC61000-4-2, ±8 kV Contact See Figures 1		e Figures 1	& 2	V
Clamping Voltage TLP (Note 1)	V <sub>C</sub>	I <sub>PP</sub> = 8 A IEC61000-4-2 Level 2 Equivalent (±4 kV Contact, ±8 kV Air)		21.3		V
		I <sub>PP</sub> = 16 A IEC61000-4-2 Level 4 Equivalent (±8 kV Contact, ±16 kV Air)		22.9		V
Reverse Peak Pulse Current	I <sub>PP</sub>	IEC61000-4-5 (8x20 μs) Input Voltage	53			V
		IEC61000-4-5 (8x20 μs) per Figure 11	11			А
Clamping Voltage 8x20 µs Waveform per Figure A (Note 2)	V <sub>C</sub>	IEC61000-4-5 (8x20 μs) Input Voltage = 53 V		23	26	V
Dynamic Resistance	R <sub>DYN</sub>	I/O Pin to GND (8x20 μs)		0.43		Ω
Junction Capacitance	CJ	V <sub>R</sub> = 0 V, f = 1 MHz		0.80	1.0	pF

## **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise specified)

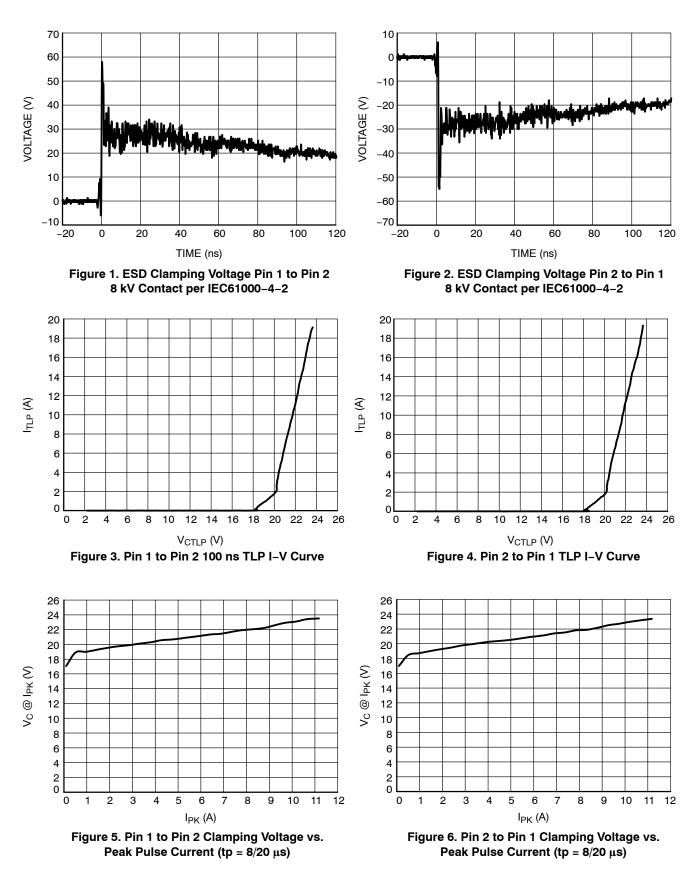
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

ANSI/ESD STM5.5.1 - Electrostatic Discharge Sensitivity Testing using Transmission Line Pulse (TLP) Model. 1.

TLP conditions: Z0 = 50, tp = 100 ns, tr = 1 ns, averaging window; t1 = 70 ns to t2 = 90 ns. 2. Non-repetitive current pulse at  $T_A = 25^{\circ}$ C, per IEC61000–4–5 waveform.

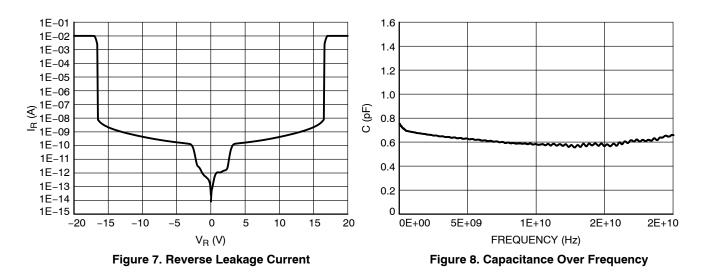
## ESDL4151

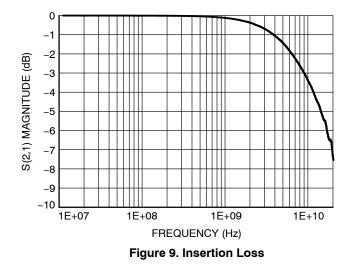
#### **TYPICAL CHARACTERISTICS**



## ESDL4151

#### **TYPICAL CHARACTERISTICS**





#### IEC 61000-4-2 Spec.

Level	Test Volt- age (kV)	First Peak Current (A)	Current at 30 ns (A)	Current at 60 ns (A)
1	2	7.5	4	2
2	4	15	8	4
3	6	22.5	12	6
4	8	30	16	8

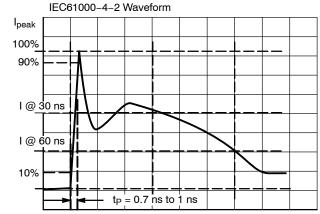


Figure 10. IEC61000-4-2 Spec

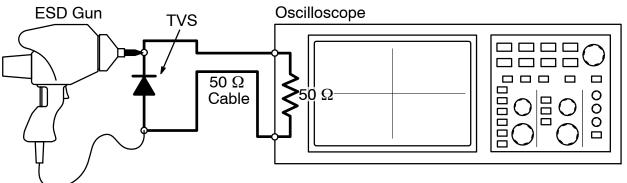
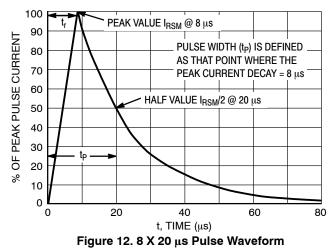


Figure 11. Diagram of ESD Test Setup

#### **ESD Voltage Clamping**

For sensitive circuit elements it is important to limit the voltage that an IC will be exposed to during an ESD event to as low a voltage as possible. The ESD clamping voltage is the voltage drop across the ESD protection diode during an ESD event per the IEC61000–4–2 waveform. Since the IEC61000–4–2 was written as a pass/fail spec for larger systems such as cell phones or laptop computers it is not clearly defined in the spec how to specify a clamping voltage

at the device level. ON Semiconductor has developed a way to examine the entire voltage waveform across the ESD protection diode over the time domain of an ESD pulse in the form of an oscilloscope screenshot, which can be found on the datasheets for all ESD protection diodes. For more information on how ON Semiconductor creates these screenshots and how to interpret them please refer to AND8307/D.



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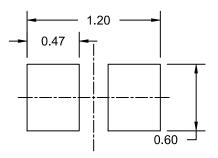
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DATE 05 DEC 2018

#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- 2. CONTROLLING DIMENSION: MILLIMETERS

	MILLIMETERS			
DIM	MIN.	NOM.	MAX.	
А	0.20	0.23	0.26	
A1	0.00		0.03	
b	0.45	0.50	0.55	
D	0.95	1.00	1.05	
E	0.55	0.60	0.65	
е	0.65 BSC			
L	0.20	0.25	0.30	
L2	0.10 REF			



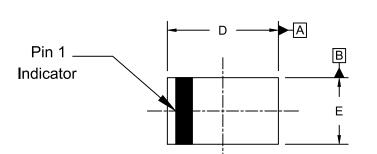
#### RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

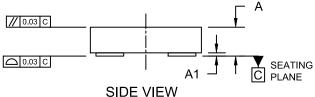
\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

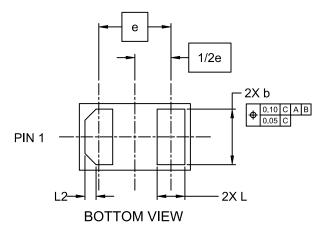
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#### GENERIC **MARKING DIAGRAM\***



XX = Specific Device Code М = Date Code

SIDE VIEW

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